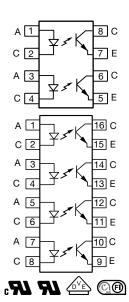


i179015-1

Vishay Semiconductors

Optocoupler, Phototransistor Output, (Dual, Quad Channel), 110 °C Rated

Dual Channel Quad Channel



LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The ILD1615, ILQ1615 are multi-channel 110 $^{\circ}$ C rated phototransistor optocouplers that use GaAs IRLED emitters and high gain NPN phototransistors. These devices are constructed using over/under leadframe optical coupling and double molded insulation technology resulting a withstand test voltage of 7500 $V_{AC\ PEAK}$ and a working voltage of 1700 V_{RMS} .

The binned min. / max. and linear CTR characteristics make these devices well suited for DC or AC voltage detection. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

Because of guaranteed maximum non-saturated and saturated switching characteristics, the ILD1615, ILQ1615 can be used in medium speed data I/O and control systems. The binned min. / max. CTR specification allow easy worst case interface calculations for both level detection and switching applications. Interfacing with a CMOS logic is enhanced by the guaranteed CTR at $I_F = 1.0$ mA.

FEATURES

• Operating temperature from -55 °C to +110 °C



RoHS

- Identical channel to channel footprint
- Dual and quad packages feature:
 - Reduced board space
 - Lower pin and parts count
 - Better channel to channel CTR match
 - Improved common mode rejection
- Isolation test voltage, 5300 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AGENCY APPROVALS

- <u>UL 1577</u>
- cUL
- DIN EN 60747-5-5 (VDE 0884), available with option 1
- FIMKO



ORDERING INFORMATION					
L		CTR BIN			
AGENCY CERTIFIED / PACKAGE	DUAL CHANNEL	QUAD CHANNEL			
AGENCY CENTIFIED / PACKAGE	CTR (%)				
UL, cUL, FIMKO 160 to 320		160 to 320			
DIP-8	ILD1615-4	-			
DIP-16	-	ILQ1615-4			

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Peak reverse voltage		V_{R}	6.0	V				
Forward current		I _F	60	mA				
Surge current		I _{FSM}	1.5	А				
Power dissipation		P _{diss}	100	mW				
Derate linearly from 25 °C			1.0	mW/°C				
ОUТРUТ								
Collector emitter breakdown voltage		BV _{CEO}	70	V				
Emitter collector breakdown voltage		BV _{ECO}	7.0	V				
0.11		I _C	50	mA				
Collector current	t < 1.0 ms	I _C	100	mA				
Power dissipation		P _{diss}	150	mW				
Derate linearly from 25 °C			1.5	mW/°C				
COUPLER								
Storage temperature		T _{stg}	-55 to +150	°C				
Operating temperature		T _{amb}	-55 to +110	°C				
Soldering temperature (1)	2.0 mm distance from case bottom	T _{sld}	260	°C				
Package power dissipation ILD1615			400	mW				
Derate linearly from 25 °C			5.33	mW/°C				
Package power dissipation ILQ1615			500	mW				
Derate linearly from 25 °C			6.67	mW/°C				

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to wave profile for soldering conditions for through hole devices



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT									
Forward voltage	I _F = 10 mA	V _F	1.0	1.15	1.3	V			
Breakdown voltage	I _R = 10 μA	V _{BR}	6.0	30	-	V			
Reverse current	V _R = 6.0 V	I _R	-	0.01	10	μA			
Capacitance	V _R = 0 V, f = 1.0 MHz	Co	-	25	-	pF			
OUTPUT									
Collector emitter capacitance	V _{CE} = 5.0 V, f = 1.0 MHz	C _{CE}	-	6.8	-	pF			
Collector emitter leakage current	ollector emitter leakage current V _{CE} = 10 V		-	5.0	100	nA			
Collector emitter breakdown voltage	I _{CE} = 0.5 mA	BV _{CEO}	70	-	-	V			
Emitter collector breakdown voltage	nitter collector breakdown voltage I _E = 0.1 mA		7.0	-	-	V			
PACKAGE TRANSFER CHARACTER	STICS								
Channel/channel CTR match	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	CTRX/CTRY	1 to 1	-	2 to 1				
COUPLER									
Capacitance (input to output)	V _{IO} = 0 V, f = 1.0 MHz	C _{IO}	-	0.8	-	pF			
Insulation resistance	V _{IO} = 500 V, T _A = 25 °C	R _S	10 ¹²	10 ¹⁴	-	Ω			
Channel to channel isolation			500	-	-	V _{AC}			

Note

Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Current transfer ratio (collector emitter saturated)	I _E = 1.0 mA, V _{CE} = 0.4 V	ILD1615-4	CTR _{CEsat}	-	100	-	%	
	$I_F = 1.0 \text{ mA}, V_{CE} = 0.4 \text{ V}$	ILQ1615-4					%	
Current transfer ratio (collector emitter)	I _F = 10 mA, V _{CE} = 5.0 V	ILD1615-4	CTR _{CE}	160	200	320	0/	
		ILQ1615-4					%	
	1 10 m 1 V 5 0 V	ILD1615-4	- CTR _{CE}	_E 56	90	-	0/	
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	ILQ1615-4					%	

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED						
Turn-on time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{on}	-	3.0	-	μs
Rise time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _r	-	2.0	-	μs
Turn-off time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{off}	-	2.3	-	μs
Fall time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _f	-	2.0	-	μs
Propagation H to L	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{PHL}	-	1.1	-	μs
Propagation L to H	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω , 50 % of V_{PP}	t _{PLH}	-	2.5	-	μs
SATURATED						
Turn-on time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _{on}	-	6.0	-	μs
Rise time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _r	-	4.6	-	μs
Turn-off time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _{off}	-	25	-	μs
Fall time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _f	-	15	-	μs
Propagation H to L	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 k Ω , V_{HT} = 1.5 V	t _{PHL}	-	5.4	=	μs
Propagation L to H	$I_F = 5.0 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 1.0 \text{ k}\Omega, V_{HT} = 1.5 \text{ V}$	t _{PLH}	-	7.4	-	μs



COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode rejection output high	$\begin{split} V_{CM} = 50 \; V_{P\text{-}P}, \; R_L = 1.0 \; k\Omega, \\ I_F = 0 \; mA \end{split}$	CM _H	-	5000	-	V/µs
Common mode rejection output low	V_{CM} = 50 V_{P-P} , R_L = 1.0 $k\Omega$, I_F = 10 mA	CML	-	5000	-	V/µs
Common mode coupling capacitance		C _{CM}	-	0.01	-	pF

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification	According to IEC 68 part 1		55 / 110 / 21				
Comparative tracking index		CTI	175				
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}			
Maximum transient isolation voltage		V _{IOTM}	10 000	V _{peak}			
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω			
Output safety power		P _{SO}	400	mW			
Input safety current		I _{SI}	275	mA			
Safety temperature		T _S	175	°C			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Insulation thickness		DTI	≥ 0.4	mm			

Note

TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

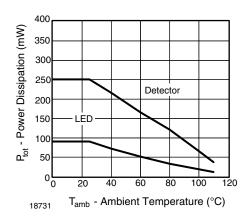


Fig. 1 - Permissible Power Dissipation vs. Temperature Non-Saturation Operation

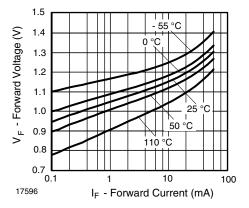


Fig. 2 - Forward Voltage vs. Forward Current

[•] As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



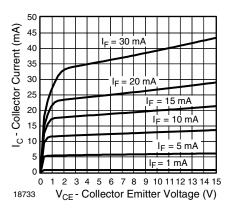


Fig. 3 - Collector Current vs. Collector Emitter Voltage

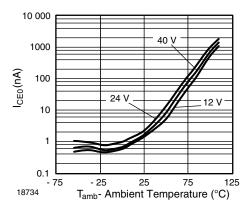


Fig. 4 - Collector to Emitter Dark Current vs. Ambient Temperature

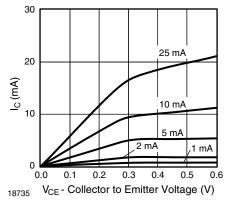


Fig. 5 - Normalized Current vs. Collector Emitter Saturation Voltage

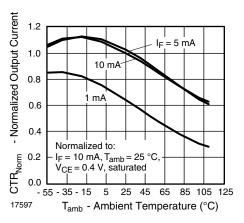


Fig. 6 - Normalized Current Transfer Ratio vs. Ambient Temperature

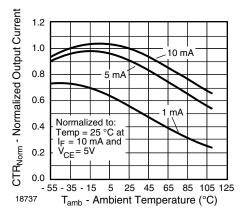


Fig. 7 - Normalized CTR vs. Temperature

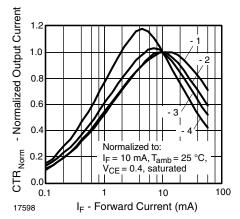


Fig. 8 - Normalized CTR vs. Forward Current



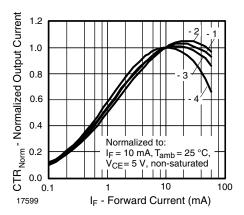


Fig. 9 - Normalized CTR vs. Forward Current

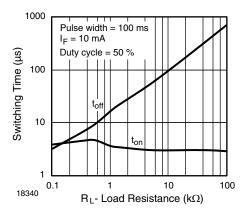


Fig. 10 - Forward Resistance vs. Forward Current

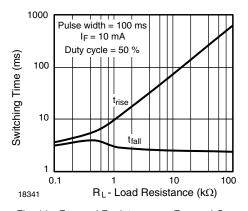
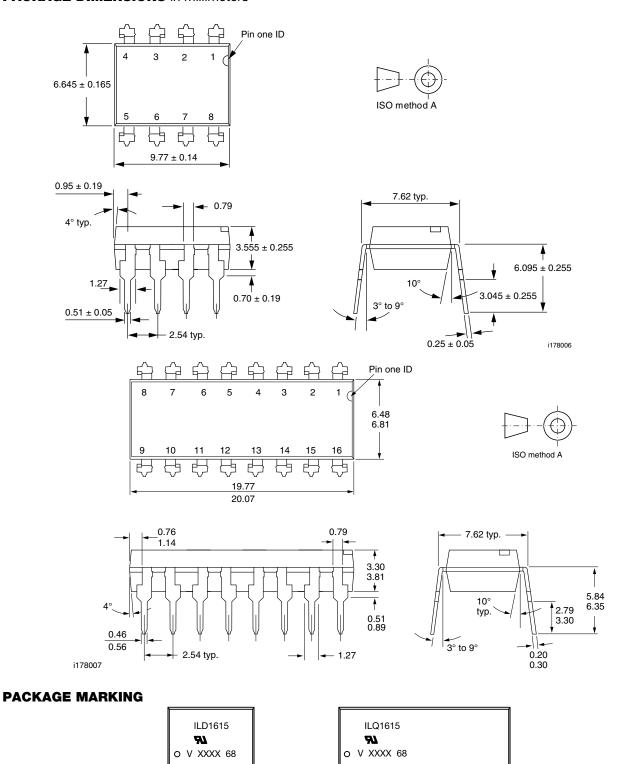


Fig. 11 - Forward Resistance vs. Forward Current



PACKAGE DIMENSIONS in millimeters



Note

• XXXX = LMC (lot marking code)



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